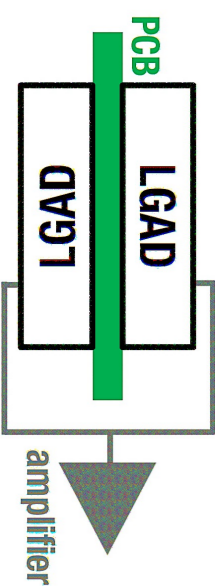


Innovations in silicon detector technologies for next-generation experiments: improving timing precision of LGADs for ALICE 3

Sofia Strazzi (University and INFN, Bologna) on behalf of the ALICE Collaboration

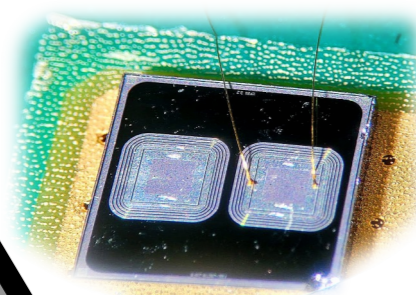
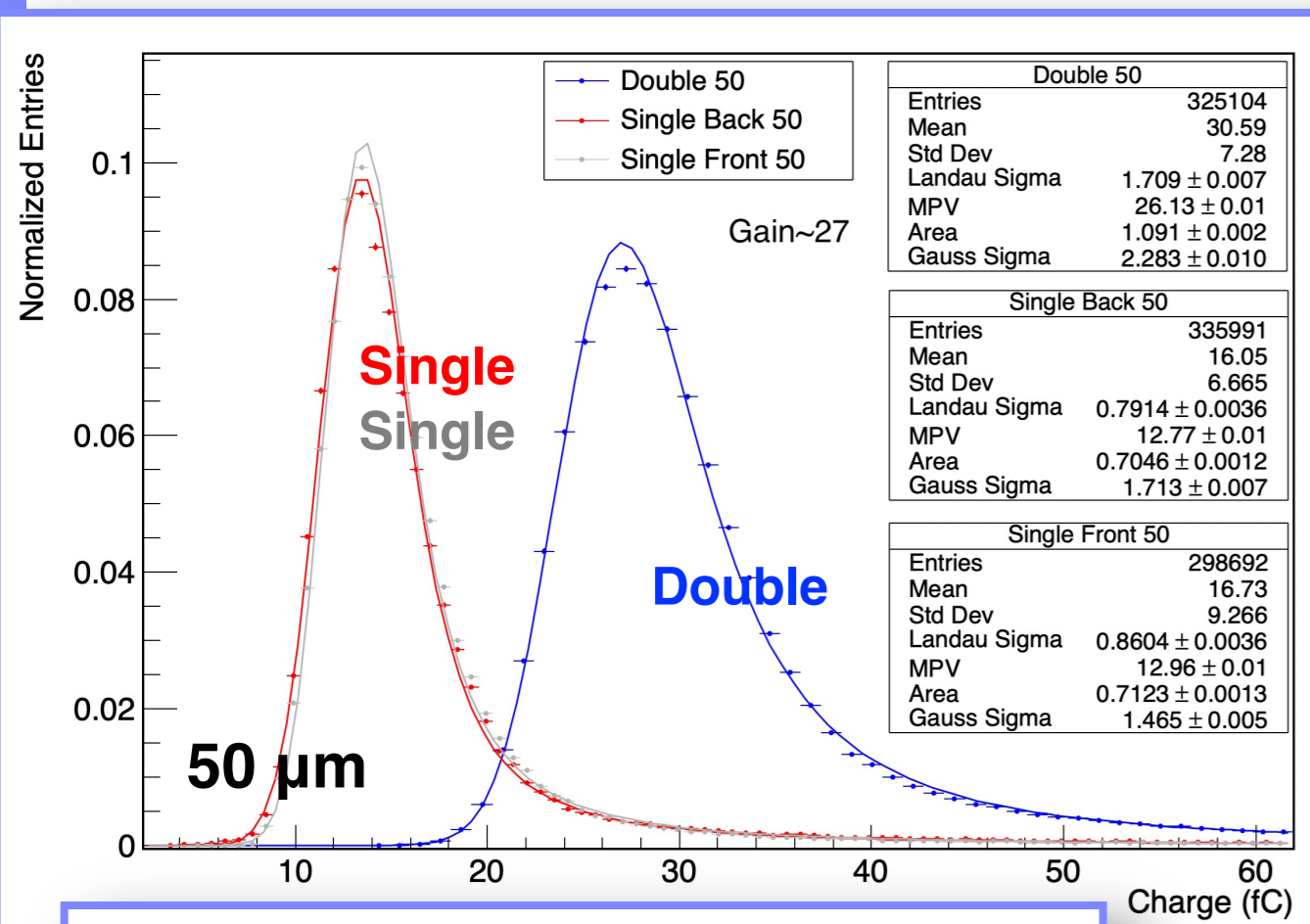
The new double-LGAD concept

was introduced and tested for the first time.



It consists of summing up the signals generated by two layers of LGAD using a single front-end amplifier.

→ higher (doubled) charge at the input of the amplifier for all the thicknesses

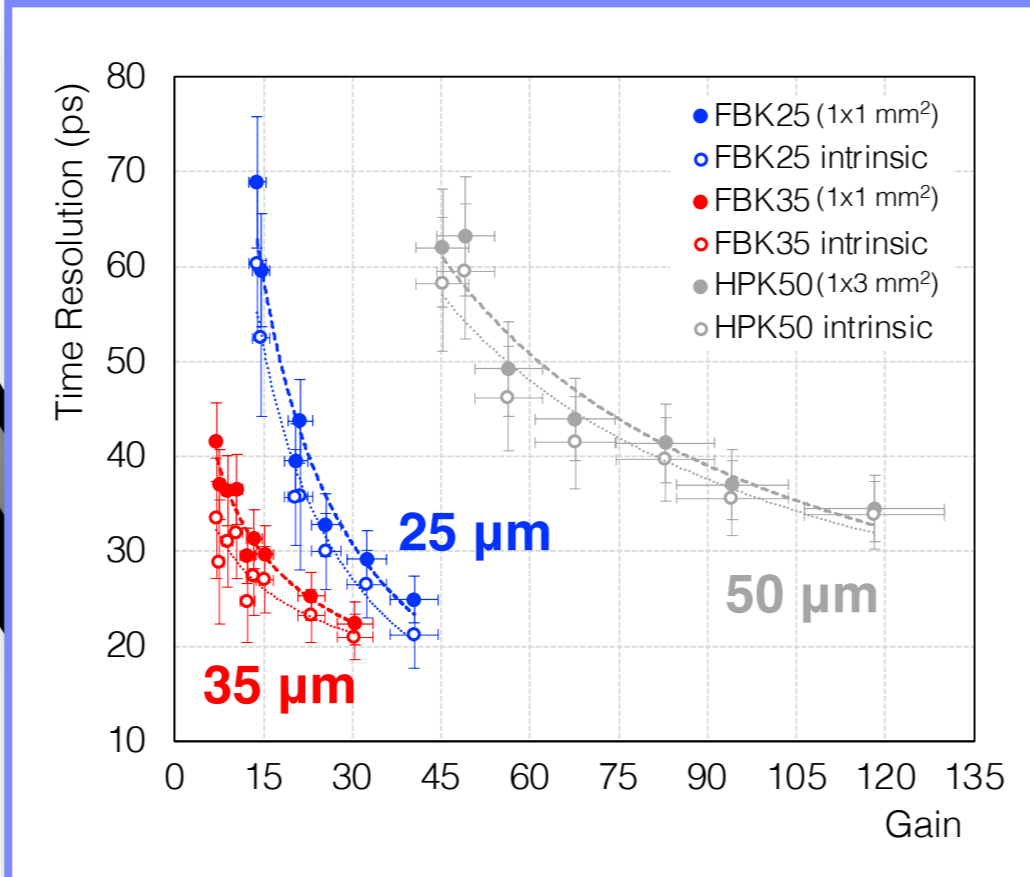
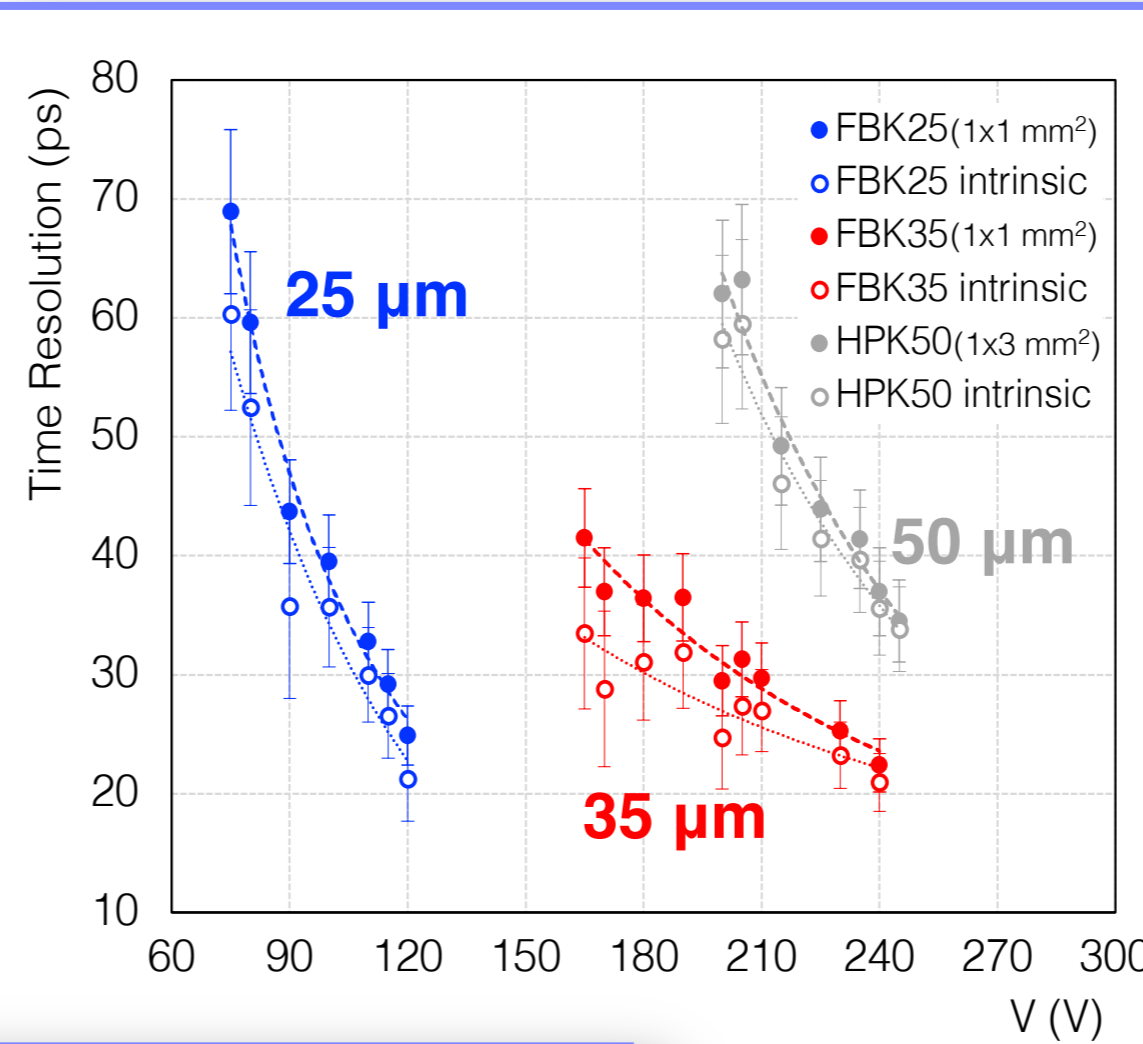


Very thin LGADs (25 & 35 μm)

were tested for the first time in a test beam setup.

→ Improvement of the time resolution by going to a thinner LGAD design

<https://doi.org/10.1140/epj/p/s13360-022-03619-1>



25 μm (120 V) → 25 ps

35 μm (240 V) → 22 ps

(different doping concentrations in the two thicknesses)

<https://doi.org/10.1140/epj/p/s13360-023-04621-x>

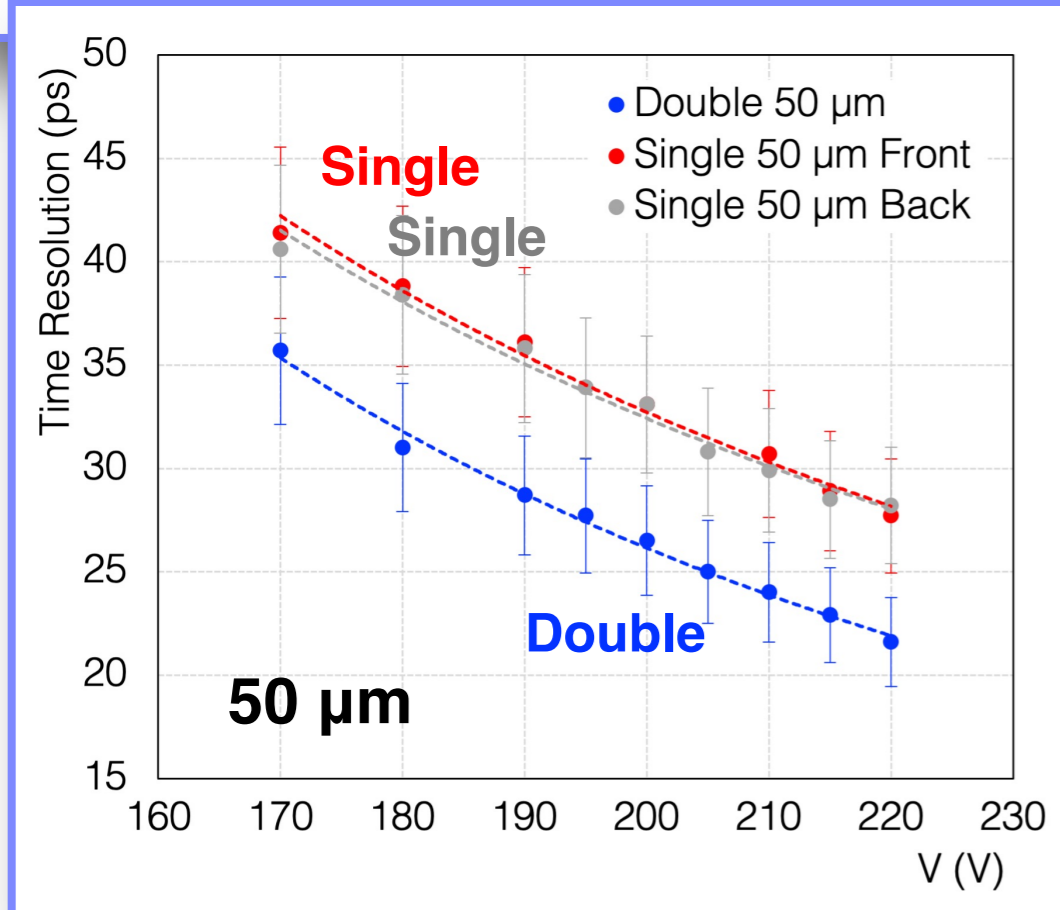
→ advantage for the electronics

Ongoing

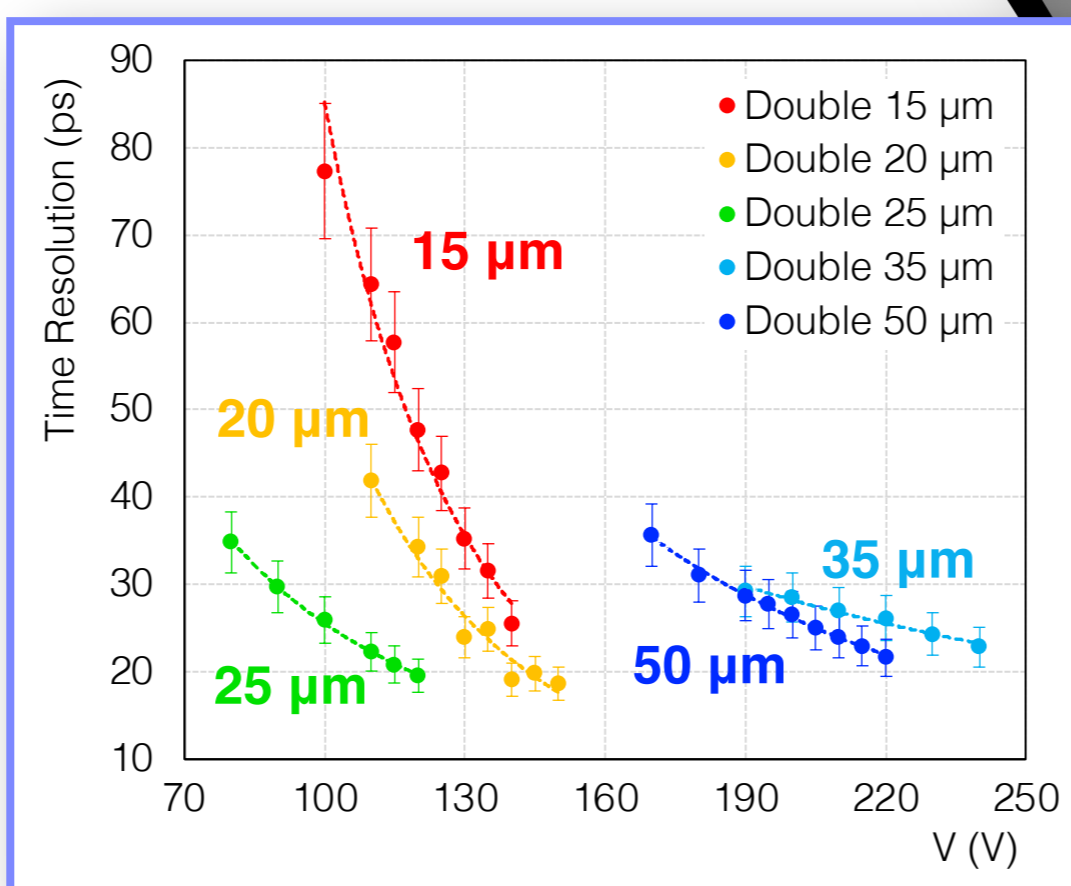
• Studies of the time resolution with an electronics chain with LIROC + picoTDC

• Studies on CMOS-LGADs

→ consistent improvement of the time resolution for the d-LGAD compared to the single LGADs



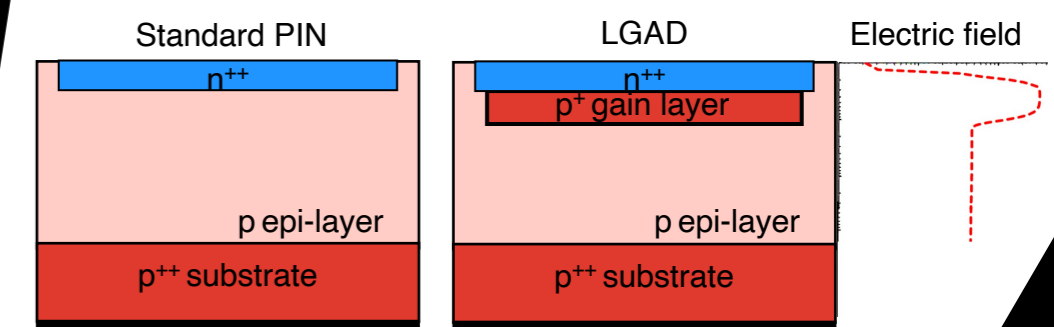
Studies then done on even thinner LGADs (15 & 20 μm):



→ Time resolution of ~20 ps for all thicknesses (15 to 50 μm) and below ~20 ps for 20 μm

LGADs are silicon detectors developed to detect charged particles.

→ They are an evolution of *n-on-p* (PIN) sensors, obtained by implanting an additional highly doped gain layer just below the *p-n* junction.



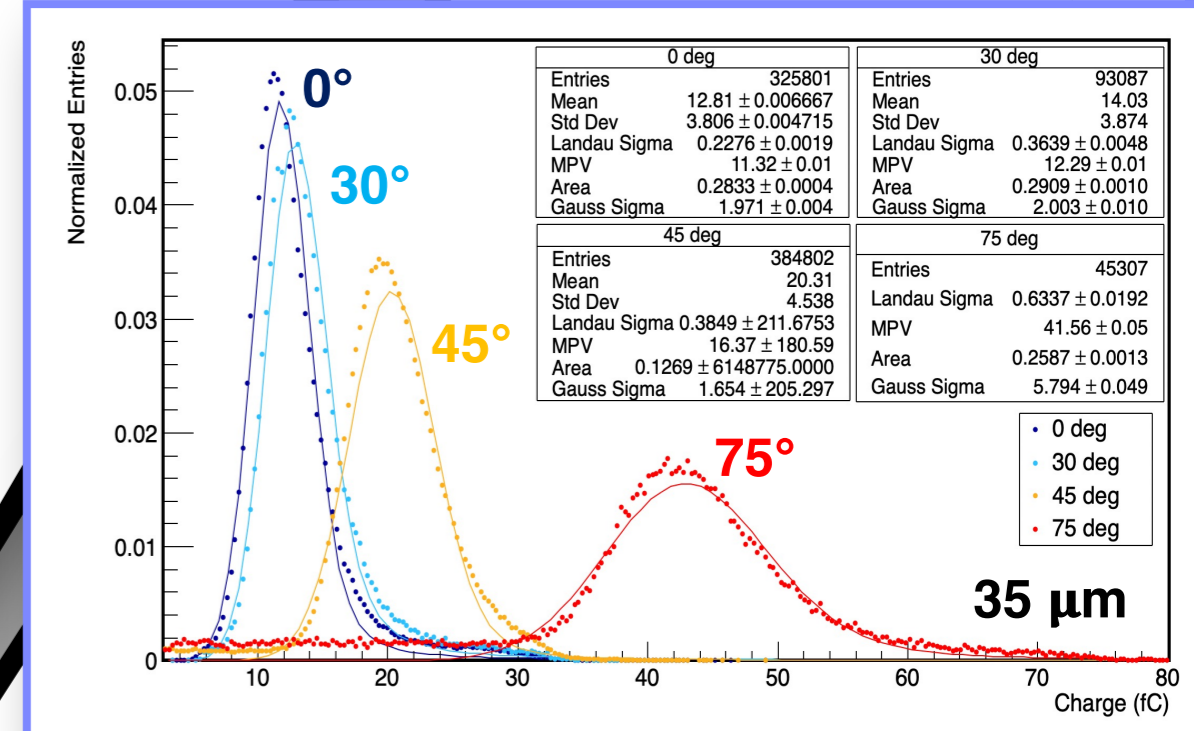
Based on internal low-gain (10-70) multiplication mechanism

Large and fast signals

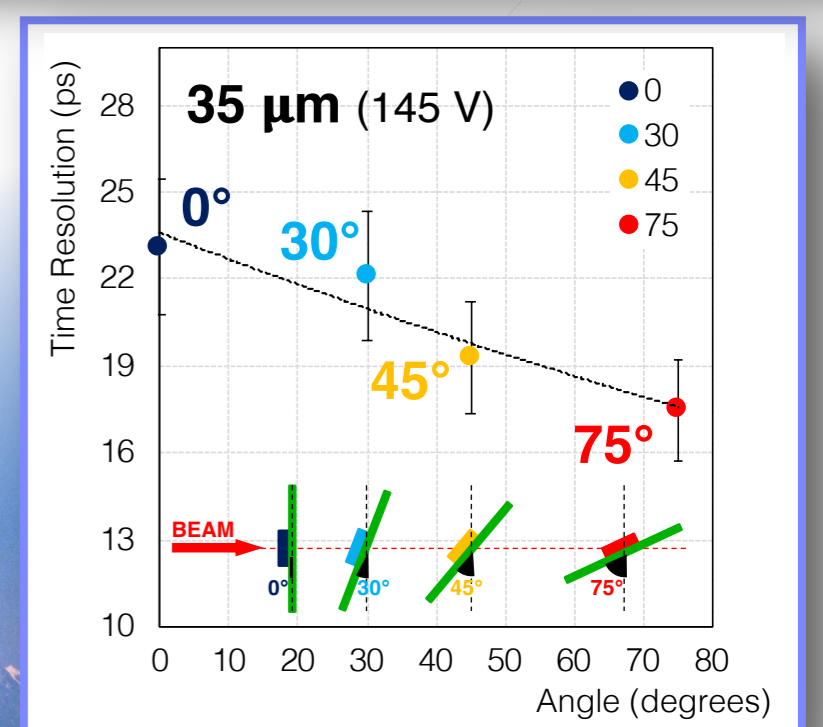
Improved S/N
Excellent timing performance

→ Most mature silicon detector technology for timing applications

Time resolution VS incident angles



Longer path inside the LGAD
Higher charge realized



The time resolution slightly improves going to higher impinging Angles.

Tilted LGADs

ALICE 3 - A next generation heavy ion experiment

TIME OF FLIGHT (TOF) DETECTOR

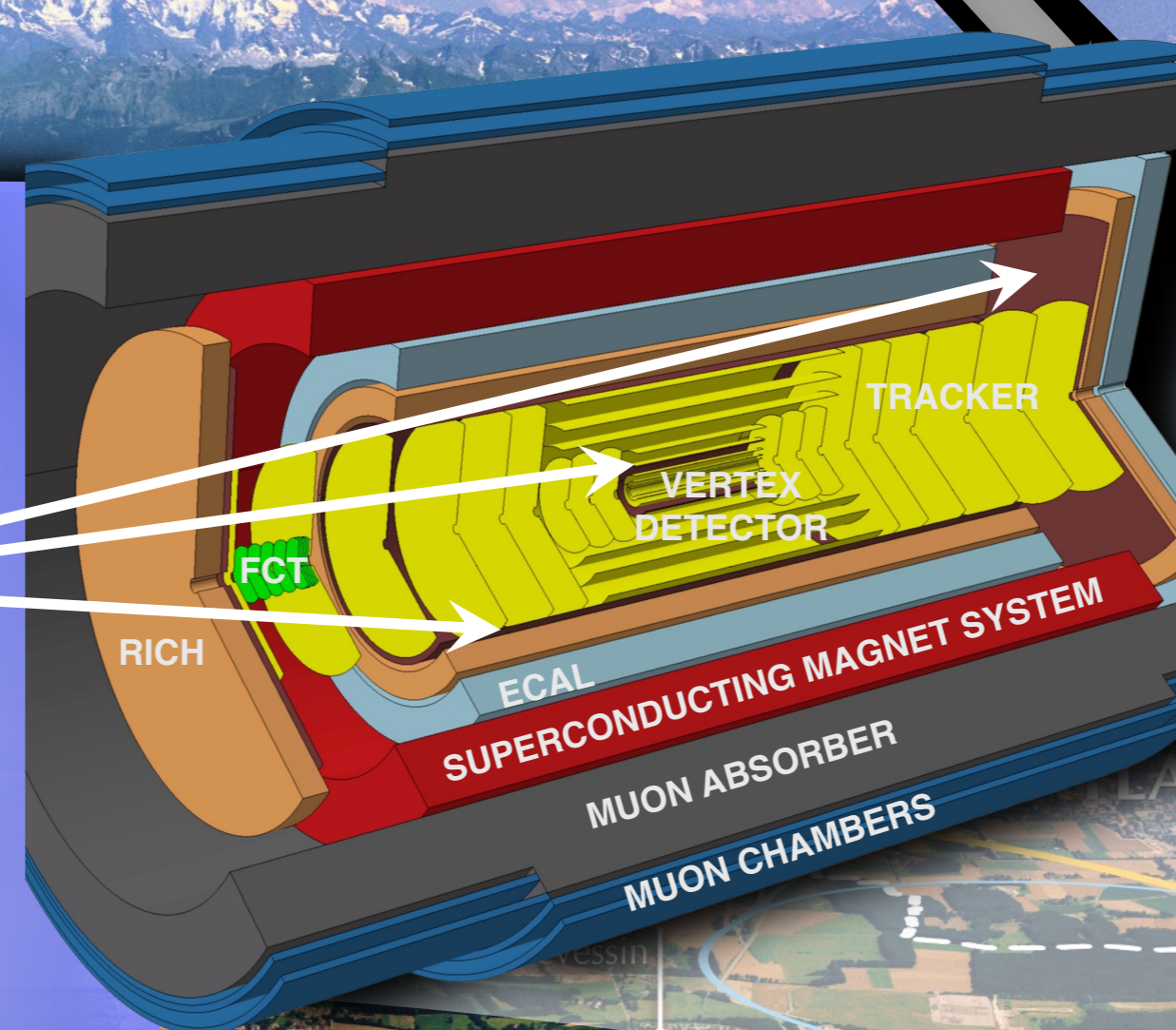
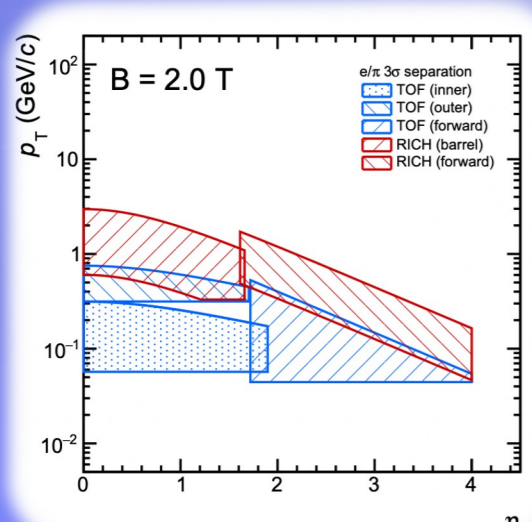
- outer TOF R ≈ 85 cm
- inner TOF R ≈ 19 cm
- forward TOF z ≈ ±375 cm

Requirements:

- Rad. hardness {
 - outer TOF: NIEL ~ 9·10¹¹ MeV n_{eq}/cm²
 - inner TOF: NIEL ~ 6.1·10¹² MeV n_{eq}/cm²
 - forward TOF: NIEL ~ 8.5·10¹² MeV n_{eq}/cm²

• Time resolution of 20 ps

Extensive R&D on the most advanced silicon technologies: LGADs, SiPMs, CMOS LGADs



ALICE 3	2024-2025	2026-2028	2029-2032	2033-2034	2035-2038	2039	2040-2041
LHC Run 3	LHC LS3	LHC Run 4	LHC LS4	LHC Run 5	LHC LS5	LHC Run 6	